

800G OSFP112 DR8 LPO FNT Pluggable Optical Transceiver

Features

- OSFP MSA 5.0 and CMIS 5.1 compliant
- Dual MPO-12/APC optical connectors
- 8x106.25Gbps (53.125GBd PAM4) electrical interface
- 8x106.25Gbps (53.125GBd PAM4) optical interface
- Up to 500m over SMF
- Power dissipation $\leq 9W$
- Operating case temperature: 0°C to 70°C
- IEEE802.3ck and IEEE 802.3df compliant
- Built-in digital diagnostic functions
- 3.3V power supply voltage
- RoHS compliant



Applications

- 800G Ethernet
- Data center networks
- InfiniBand NDR

Product Description

The PhoScale PHOS-8OFSD85M16L transceiver is designed for 800G Ethernet and InfiniBand communication application links over 500m of single-mode fiber (SMF), and it is compliant with OSFP MSA, 800G Pluggable MSA, CMIS 5.1, IEEE802.3ck and IEEE 802.3df standards. The PHOS-8OFSD85M16L uses LPO solution. It is a high-performance, low-power, low-latency and cost-effective module. The module contains 8 parallel channels on the transmitter and receiver, each operating at 106.25Gbps. The optical signal is transmitted over eight parallel channels at a central wavelength of 1310nm. The optical interface is dual MPO-12/APC connector.

Absolute Maximum Ratings

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{cc}	-0.5	-	3.6	V
Storage Temperature	T_{sto}	-40		85	°C
Relative Humidity (Non-condensing)	RH	5		95	%
Control Input Voltage	V_i	-0.3		$V_{cc}+0.5$	

NOTE: Exceeding these ratings may damage the device permanently.

Specified Operations Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Power Supply Voltage	V_{cc}	3.135	3.3	3.465	V
Power Supply Current	I_{cc}			2875	mA
Power Dissipation				9	W
Case Operating Temperature	T_{op}	0	-	70	°C
Relative Humidity (Non-condensing)	RH	15		85	%
I2C Clock Frequency			100	400	kHz

Electrical Characteristics

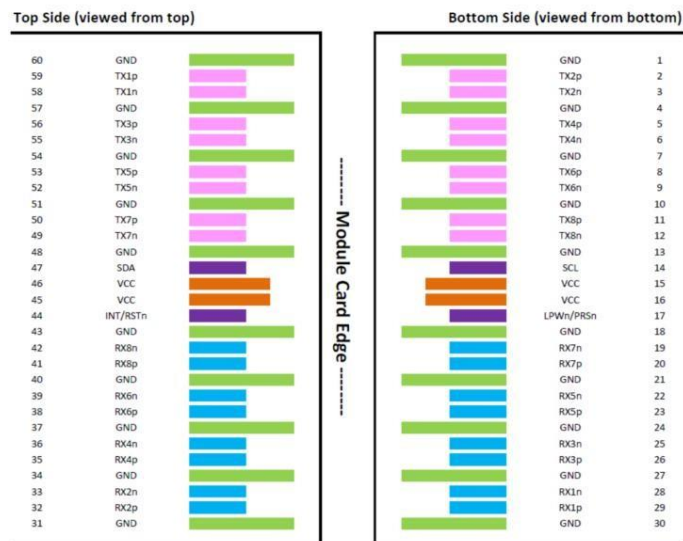
Parameter	Symbol	Min	Typ	Max	Unit
Power On Initialization Time	T_{init}			2000	ms
Transmitter					
Signaling Speed, each lane			53.125		GBd
Signaling Speed Tolerance		-100		+100	ppm
Differential pk-pk input voltage tolerance	$V_{in,pp}$	750			mV
AC common-mode RMS voltage tolerance		25			mV
Differential Input Impedance	Z_{in}	90	100	110	Ohms
Effective return loss	ERL	8.5			dB
Single-ended voltage tolerance range		-0.4		3.3	V
DC Common Mode Voltage		-0.35		2.85	V
Receiver					
Signaling Speed, each lane			53.125		GBd
Signaling Speed Tolerance		-100		+100	ppm
Differential pk-pk output voltage Short mode Long mode	$V_{out,pp}$			600 845	mV
Eye Height	EH	15			mV
Differential Output Impedance	Z_{out}	90	100	110	Ohms
Transition Time, 20% to 80%	T_r, T_f	8.5			ps
DC Common Mode Voltage		-0.35		2.85	V
AC Common Mode output Voltage (RMS)		25			mV

Optical Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Notes
Transmitter						
Signaling Speed			53.125		GBd	1
Signaling Speed Tolerance		-100		+100	ppm	
Modulation Format		PAM4				
Lane Wavelength	λ	1304.5	1311	1317.5	nm	
Side Mode Suppression Ratio	SMSR	30			dB	
Average TX Power	P_{avg}	-2.9		4	dBm	1
Outer Optical Modulation Amplitude for TDECQ < 1.4dB for 1.4dB ≤ TDECQ ≤ 3.4dB	OMA_{outer}	-0.8 -2.2+TDECQ		4.2	dBm	1
Extinction Ratio	ER	3.5			dB	1
Avg Launch Power TX Off	P_{off}			-15	dBm	1
Transmitter and dispersion eye closure for PAM4	TDECQ			3.4	dB	1
Transmitter eye closure for PAM4	TECQ			3.4	dB	
TDECQ - TECQ				2.5	dB	
Transmitter transition time				17	ps	
Relative Intensity Noise	RIN			-136	dB/Hz	
Optical Return Loss	ORTL			21.4	dB	
Reflectance				-26	dB	
Receiver						
Signaling Speed			53.125		GBd	1
Signaling Speed Tolerance		-100		+100	ppm	
Modulation Format		PAM4				
Lane Wavelength	λ	1304.5	1311	1317.5	nm	
Damage Threshold		5			dBm	1
Average RX Power		-5.9		4	dBm	1
RX Power (OMA_{outer})				4.2	dBm	1
RX Reflectance				-26	dBm	
RX Sensitivity (OMA_{outer}) for TECQ < 1.4dB for 1.4dB ≤ TECQ ≤ 3.4dB				-3.9 -5.3+TECQ	dBm	2
Stressed RX Sensitivity (OMA_{outer})				-1.9	dBm	
Conditions of Stressed RX Sensitivity Test						
Stressed Eye Closure, lane under test	SECQ	3.4			dB	
OMA_{outer} of Each Aggressor Lane		4.2				

1. Each lane.
2. Measured with conformance test signal at TP3 for BER=2.4x10⁻⁴.

Electrical Input/Output

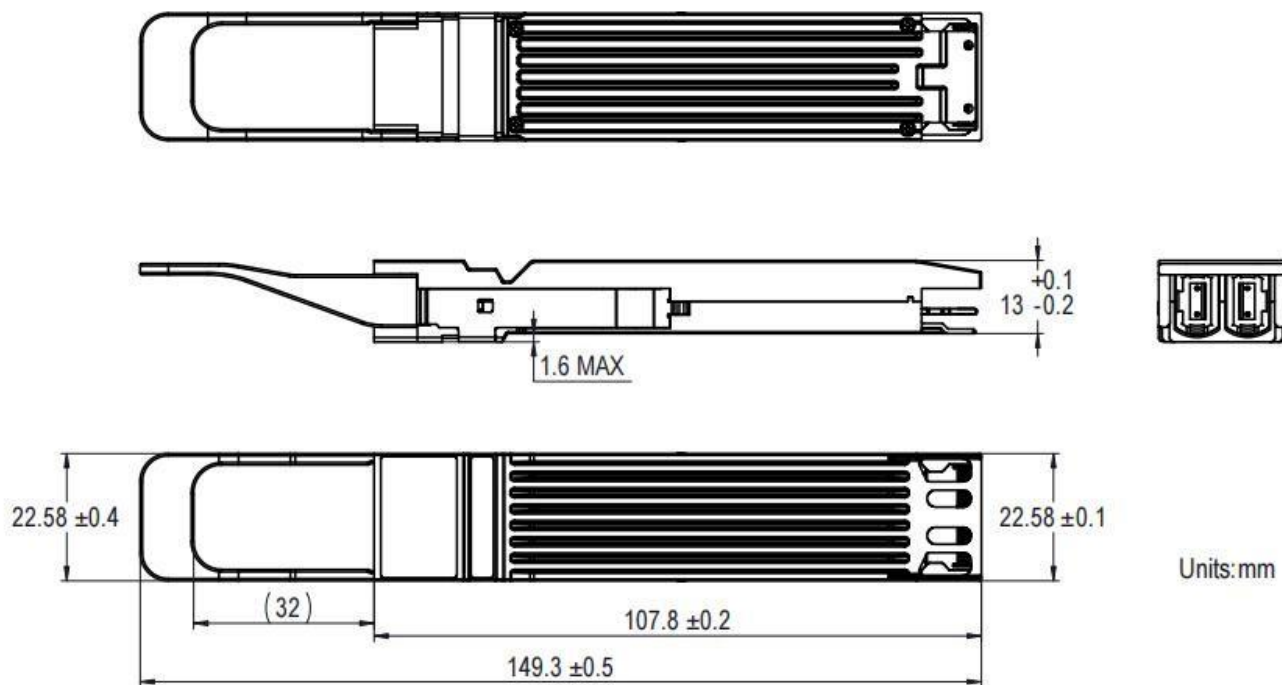


OSFP Module contact pad electrical definition

PIN	Symbol	Logic	Description	Notes
1	GND		Ground	
2	TX2p	CML-I	Transmitter Data Non-Inverted	
3	TX2n	CML-I	Transmitter Data Inverted	
4	GND		Ground	
5	TX4p	CML-I	Transmitter Data Non-Inverted	
6	TX4n	CML-I	Transmitter Data Inverted	
7	GND		Ground	
8	TX6p	CML-I	Transmitter Data Non-Inverted	
9	TX6n	CML-I	Transmitter Data Inverted	
10	GND		Ground	
11	TX8p	CML-I	Transmitter Data Non-Inverted	
12	TX8n	CML-I	Transmitter Data Inverted	
13	GND		Ground	
14	SCL	LVC MOS-I/O	2-wire Serial interface clock	Open-Drain with pull up resistor on Host
15	VCC	Power from Host	+3.3V Power	
16	VCC	Power from Host	+3.3V Power	
17	LPWn/PRSn	Multi-Level	Low-Power Mode / Module Present	See pin description for required circuit
18	GND		Ground	
19	RX7n	CML-O	Receiver Data Inverted	
20	RX7p	CML-O	Receiver Data Non-Inverted	

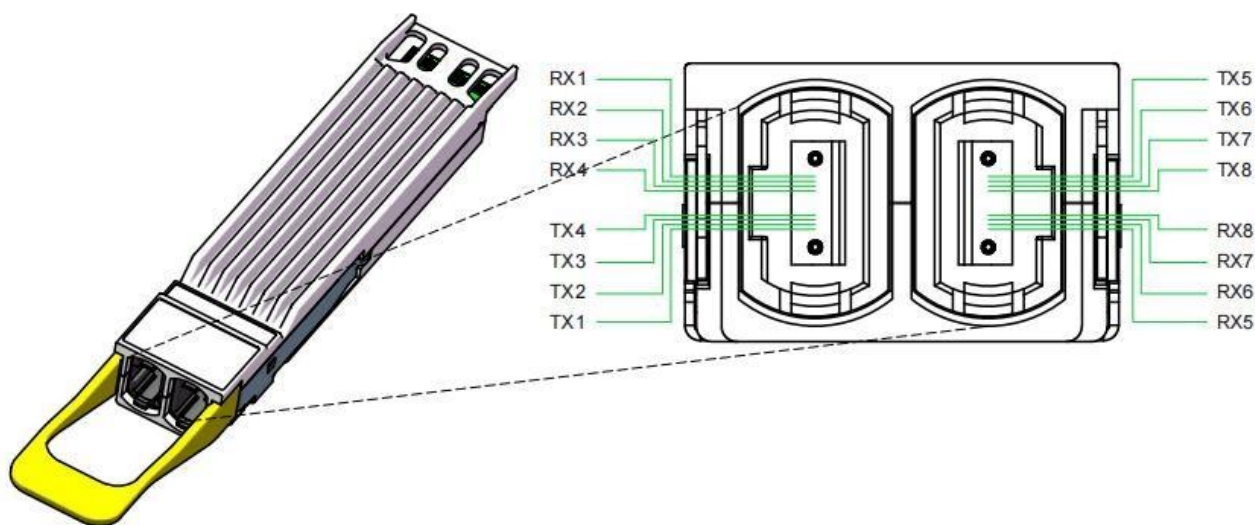
PIN	Symbol	Logic	Description	Notes
21	GND		Ground	
22	RX5n	CML-O	Receiver Data Inverted	
23	RX5p	CML-O	Receiver Data Non-Inverted	
24	GND		Ground	
25	RX3n	CML-O	Receiver Data Inverted	
26	RX3p	CML-O	Receiver Data Non-Inverted	
27	GND		Ground	
28	RX1n	CML-O	Receiver Data Inverted	
29	RX1p	CML-O	Receiver Data Non-Inverted	
30	GND		Ground	
31	GND		Ground	
32	RX2p	CML-O	Receiver Data Non-Inverted	
33	RX2n	CML-O	Receiver Data Inverted	
34	GND		Ground	
35	RX4p	CML-O	Receiver Data Non-Inverted	
36	RX4n	CML-O	Receiver Data Inverted	
37	GND		Ground	
38	RX6p	CML-O	Receiver Data Non-Inverted	
39	RX6n	CML-O	Receiver Data Inverted	
40	GND		Ground	
41	RX8p	CML-O	Receiver Data Non-Inverted	
42	RX8n	CML-O	Receiver Data Inverted	
43	GND		Ground	
44	INT/RSTn	Multi-Level	Module Interrupt / Module Reset	See pin description for required circuit
45	VCC	Power from Host	+3.3V Power	
46	VCC	Power from Host	+3.3V Power	
47	SDA	LVC MOS-I/O	2-wire Serial interface data	Open-Drain with pull up resistor on Host
48	GND		Ground	
49	TX7n	CML-I	Transmitter Data Inverted	
50	TX7p	CML-I	Transmitter Data Non-Inverted	
51	GND		Ground	
52	TX5n	CML-I	Transmitter Data Inverted	
53	TX5p	CML-I	Transmitter Data Non-Inverted	
54	GND		Ground	
55	TX3n	CML-I	Transmitter Data Inverted	
56	TX3p	CML-I	Transmitter Data Non-Inverted	
57	GND		Ground	
58	TX1n	CML-I	Transmitter Data Inverted	
59	TX1p	CML-I	Transmitter Data Non-Inverted	
60	GND		Ground	

Mechanical Specifications



Product shall be of design, construction, and physical dimensions specified on the applicable product drawing.

Optical Interface



Laser Safety

This is a Class 1 Laser Product as defined by IEC 60825-1:2014. When operated within the limits of this specification it is considered non-hazardous. Operating this product in a manner inconsistent with specifications and intended usage may result in hazardous radiation exposure.



Regulatory Certifications

This product is certified to the following regulatory standards:

Category	Standard
Radiated Emissions	EMC Directive 2014/30/EU EN 55032 CISPR 32 FCC rules 47 CFR Part 15 ICES-003 VCCI-CISPR 32 AS/NZS CISPR 32
Radiated Immunity	EMC Directive 2014/30/EU EN 55035 CISPR 35 IEC/EN 61000-4-3
RoHS	EU RoHS (2011/65/EU & (EU) 2015/863) & UK RoHS EN IEC 63000:2018 & BS EN IEC 63000:2018
Flammability (PCB)	UL Class 94 V-0

Ordering Information

Part No.	Data Rate	Wavelength	Max Distance	Case Temperature Range
PHOS-8OFSD85M16L	850Gbps	1310nm	500m	0°C to 70°C

Notice

PhoScale reserves the right to change specifications of products identified in this datasheet without notice. Applications described herein are for illustrative purposes only, and PhoScale makes no warranty that identified products will be suitable for the described applications without further testing and/or modification.